

查询"2SK3453"供应商 [TOSHIBA](#) Field Effect Transistor Silicon N Channel MOS Type ( $\pi$ -MOSV)

# 2SK3453

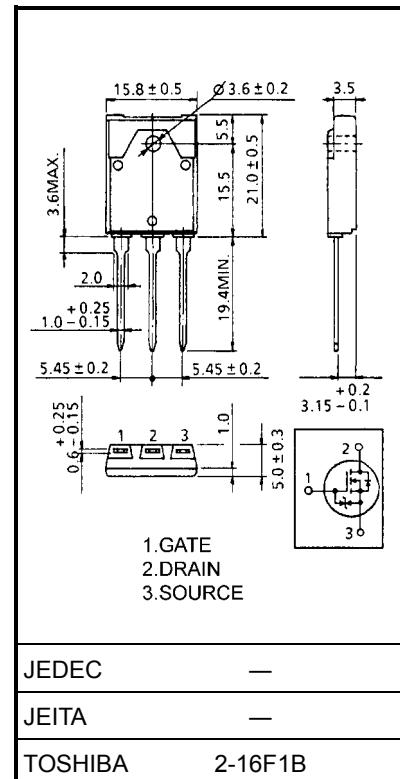
## Switching Regulator Applications

Unit: mm

- Low drain-source ON resistance:  $R_{DS(ON)} = 0.72 \Omega$  (typ.)
- High forward transfer admittance:  $|Y_{fs}| = 7.0 \text{ S}$  (typ.)
- Low leakage current:  $I_{DSS} = 100 \mu\text{A}$  (max) ( $V_{DS} = 700 \text{ V}$ )
- Enhancement-model:  $V_{th} = 2.0 \sim 4.0 \text{ V}$  ( $V_{DS} = 10 \text{ V}$ ,  $I_D = 1 \text{ mA}$ )

## Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Characteristics	Symbol	Rating	Unit
Drain-source voltage	$V_{DSS}$	700	V
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )	$V_{DGR}$	700	V
Gate-source voltage	$V_{GSS}$	$\pm 30$	V
Drain current	DC (Note 1)	$I_D$	10
	Pulse (Note 1)	$I_{DP}$	30
Drain power dissipation ( $T_c = 25^\circ\text{C}$ )	$P_D$	80	W
Single pulse avalanche energy (Note 2)	$E_{AR}$	420	mJ
Avalanche current	$I_{AR}$	10	A
Repetitive avalanche energy (Note 3)	$E_{AR}$	8	mJ
Channel temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage temperature range	$T_{stg}$	-55~150	$^\circ\text{C}$



Weight: 5.8 g (typ.)

## Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	$R_{th}(ch-c)$	1.56	$^\circ\text{C/W}$
Thermal resistance, channel to ambient	$R_{th}(ch-a)$	41.6	$^\circ\text{C/W}$

Note 1: Please use devices on condition that the channel temperature is below  $150^\circ\text{C}$ .

Note 2:  $V_{DD} = 90 \text{ V}$ ,  $T_{ch} = 25^\circ\text{C}$  (initial),  $L = 7.5 \text{ mH}$ ,  $R_G = 25 \Omega$ ,  $I_{AR} = 10 \text{ A}$

Note 3: Repetitive rating; pulse width limited by maximum channel temperature.

This transistor is an electrostatic sensitive device. Please handle with caution.

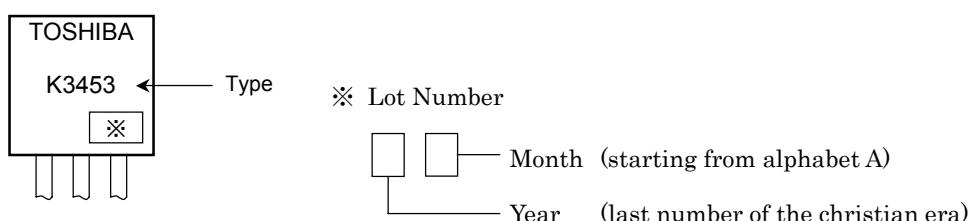
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Electrical Characteristics ( $T_a = 25^\circ C$ )

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	$I_{GSS}$	$V_{GS} = \pm 25 V, V_{DS} = 0 V$	—	—	$\pm 10$	$\mu A$
Drain-source breakdown voltage	$V_{(BR) GSS}$	$I_G = \pm 10 \mu A, V_{DS} = 0 V$	$\pm 30$	—	—	V
Drain cut-OFF current	$I_{DSS}$	$V_{DS} = 700 V, V_{GS} = 0 V$	—	—	100	$\mu A$
Drain-source breakdown voltage	$V_{(BR) DSS}$	$I_D = 10 mA, V_{GS} = 0 V$	700	—	—	V
Gate threshold voltage	$V_{th}$	$V_{DS} = 10 V, I_D = 1 mA$	2.0	—	4.0	V
Drain-source ON resistance	$R_{DS (\text{ON})}$	$V_{GS} = 10 V, I_D = 5 A$	—	0.72	1.0	$\Omega$
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 10 V, I_D = 5 A$	4.0	7.0	—	S
Input capacitance	$C_{iss}$	$V_{DS} = 25 V, V_{GS} = 0 V, f = 1 MHz$	—	1700	—	pF
Reverse transfer capacitance	$C_{rss}$		—	40	—	
Output capacitance	$C_{oss}$		—	200	—	
Switching time	Rise time	$t_r$		—	40	—
	Turn-ON time	$t_{on}$		—	72	—
	Fall time	$t_f$		—	42	—
	Turn-OFF time	$t_{off}$		—	145	—
Total gate charge (gate-source plus gate-drain)	$Q_g$	$V_{DD} \approx 400 V, V_{GS} = 10 V, I_D = 10 A$	—	53	—	nC
Gate-source charge	$Q_{gs}$		—	25	—	
Gate-drain ("miller") charge	$Q_{gd}$		—	28	—	

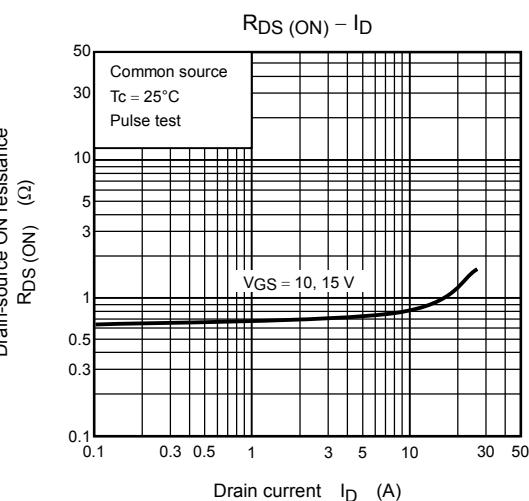
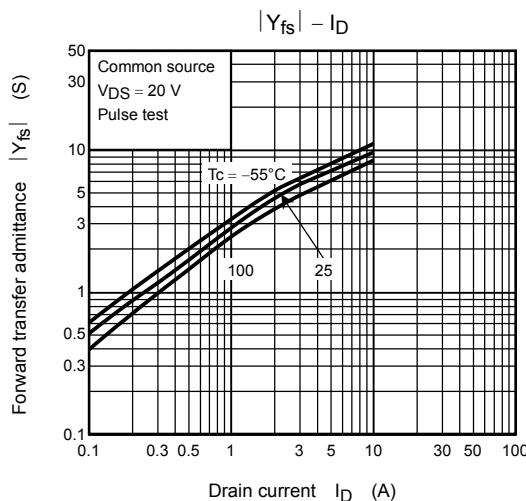
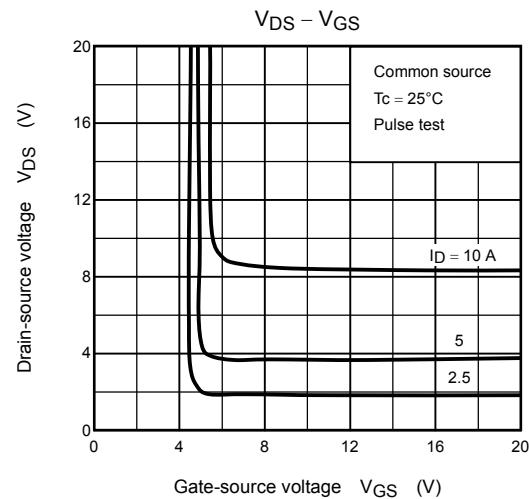
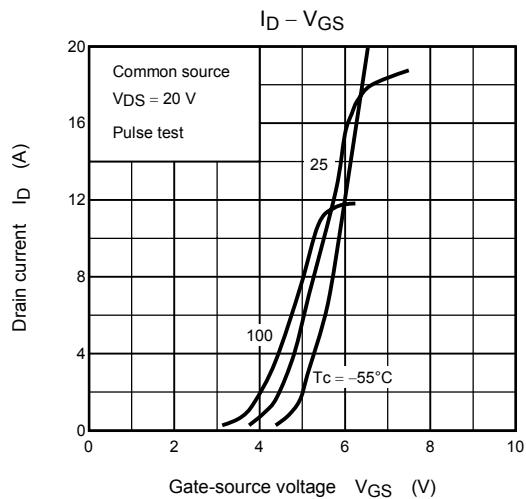
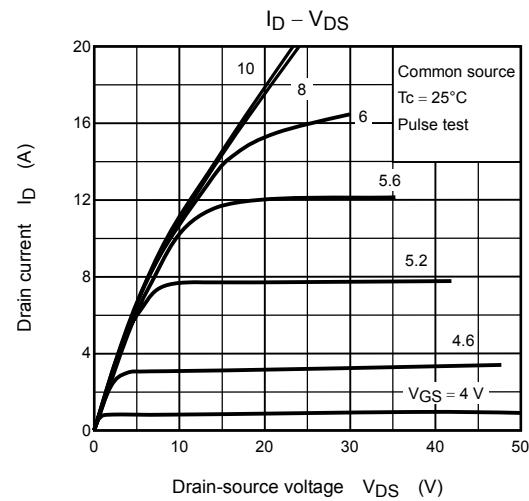
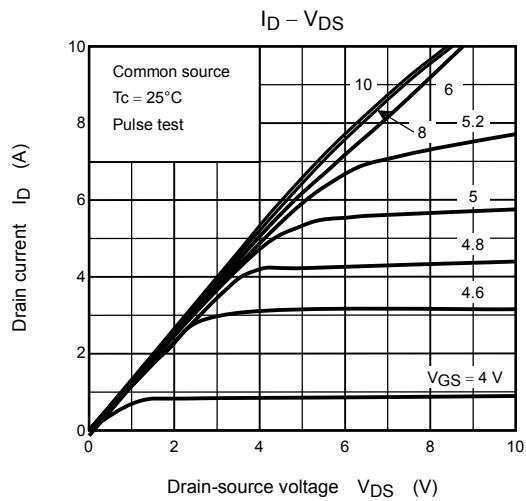
### Source-Drain Ratings and Characteristics ( $T_a = 25^\circ C$ )

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Continuous drain reverse current (Note 1)	$I_{DR}$	—	—	—	10	A
Pulse drain reverse current (Note 1)	$I_{DRP}$	—	—	—	30	A
Forward voltage (diode)	$V_{DSF}$	$I_{DR} = 10 A, V_{GS} = 0 V$	—	—	-1.9	V
Reverse recovery time	$t_{rr}$	$I_{DR} = 10 A, V_{GS} = 0 V,$ $dI_{DR}/dt = 100 A/\mu s$	—	1400	—	ns
Reverse recovery charge	$Q_{rr}$		—	17.5	—	$\mu C$

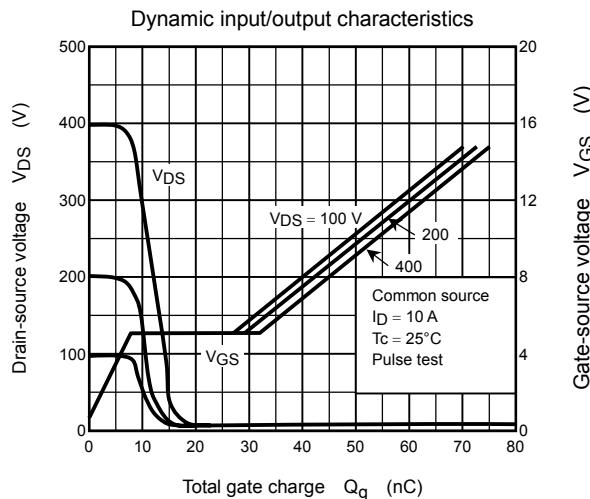
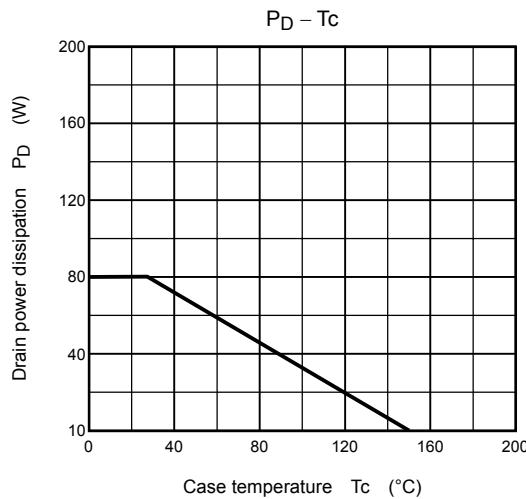
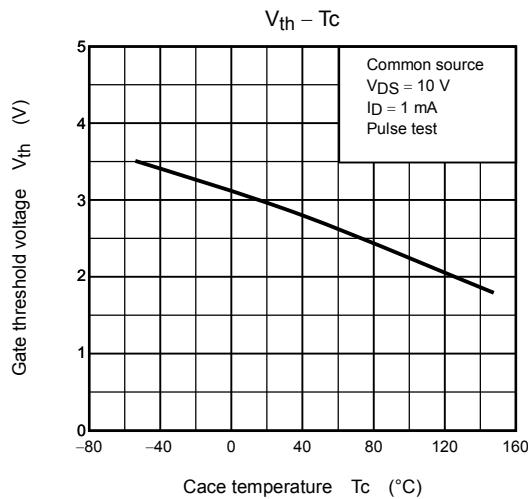
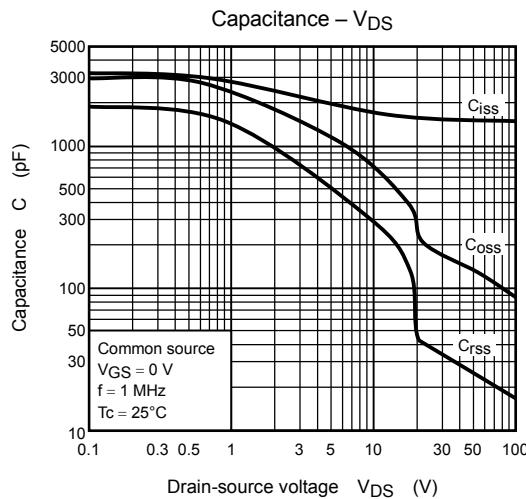
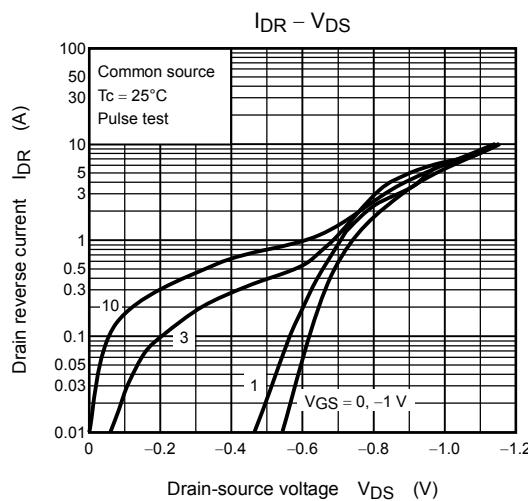
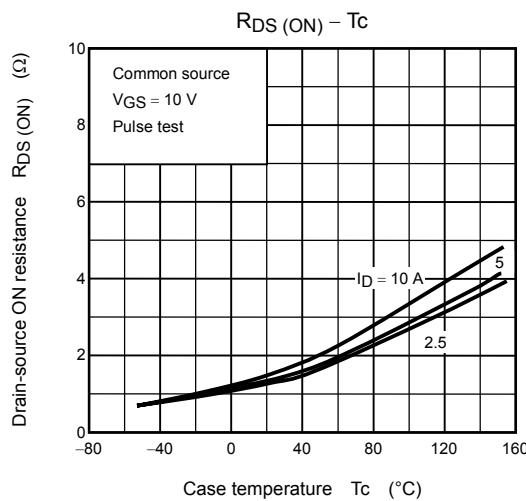
### Marking



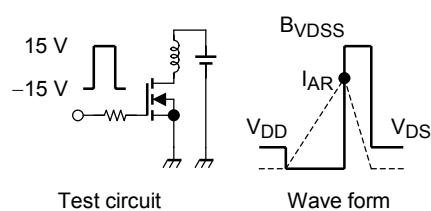
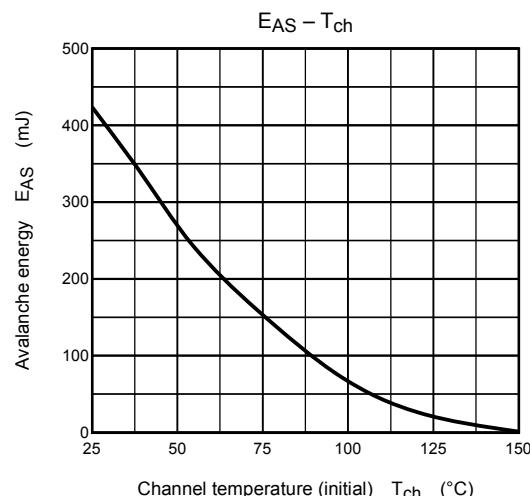
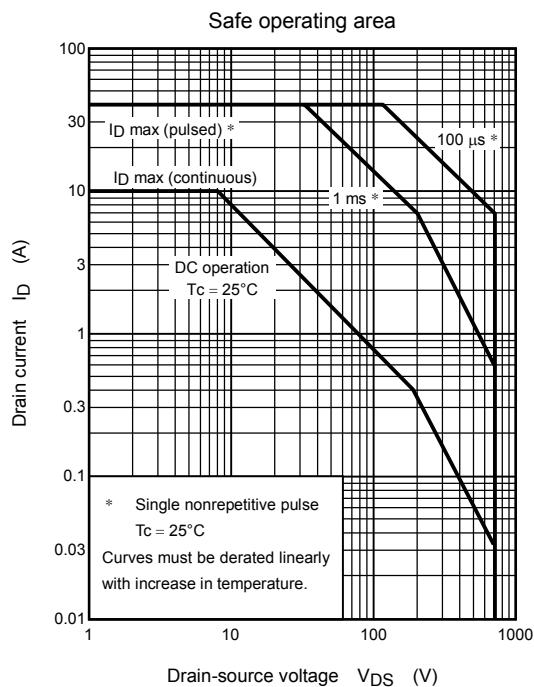
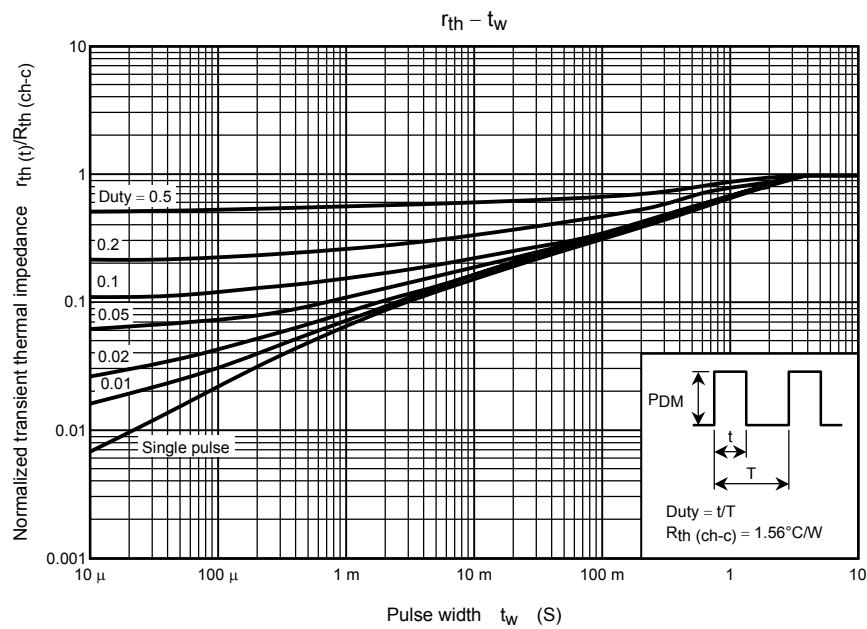
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$$R_G = 25\ \Omega$$

$$V_{DD} = 90\ \text{V}, L = 7.5\ \text{mH}$$

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left( \frac{B_{VDSS}}{B_{VDSS} - V_{DD}} \right)$$

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